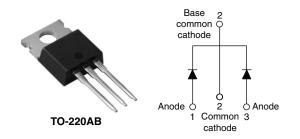
Vishay High Power Products

Schottky Rectifier, 2 x 15 A



SHA

PRODUCT SUMMARY				
I _{F(AV)}	2 x 15 A			
V _R	25/30 V			

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- · High frequency operation



- encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- · Designed and qualified for industrial level

DESCRIPTION

The 32CTQ...PbF Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	30	A		
V _{RRM}		25/30	V		
I _{FSM}	$t_p = 5 \ \mu s \ sine$	900	A		
V _F	15 Apk, T _J = 125 °C	0.40	V		
TJ	Range	- 55 to 150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	32CTQ025PbF	32CTQ030PbF	UNITS
Maximum DC reverse voltage	V _R	25	30	V
Maximum working peak reverse voltage	V _{RWM}	25	30	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 115 °C, rectangular waveform		30	
Maximum peak one cycle non-repetitive surge current	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900	A	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	250	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1.20 \text{ A}, L = 11.10 \text{ mH}$		13	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А

* Pb containing terminations are not RoHS compliant, exemptions may apply

32CTQ...PbF

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	15 A	T _J = 25 °C	0.49	v
		30 A		0.58	
		15 A	T _J = 125 °C	0.40	
		30 A		0.53	
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1.75	mA
See fig. 2	IRM (")	T _J = 125 °C		97	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		0.233	V
Forward slope resistance	r _t			9.09	mΩ
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		1300	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

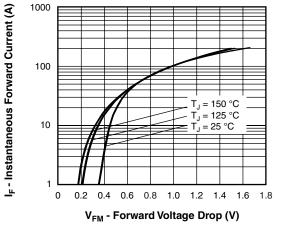
Note

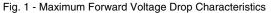
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECH	THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	rage	T _J , T _{Stg}		- 55 to 150	°C	
Maximum thermal resistan junction to case per leg	ce,	R _{thJC}	DC operation See fig. 4	3.25	°C/W	
Typical thermal resistance case to heatsink	,	R _{thCS}	Mounting surface, smooth and greased	0.50		
				2	g	
Approximate weight			0.07	0Z.		
Mounting torque ——	minimum			6 (5)	kgf ⋅ cm	
	maximum			12 (10)	(lbf · in)	
Marking device				32CT	Q025	
			Case style TO-220AB	32CT	32CTQ030	



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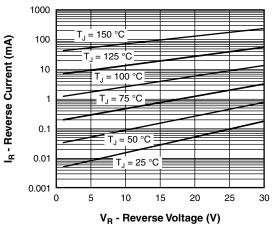


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

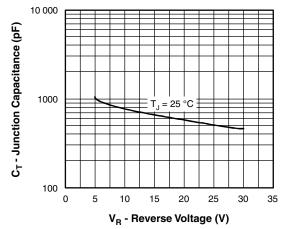


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

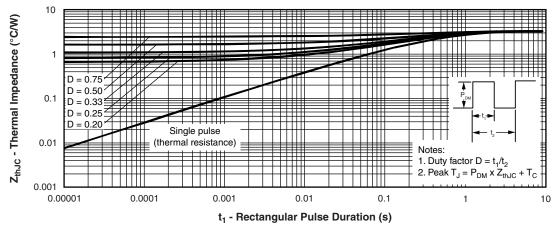
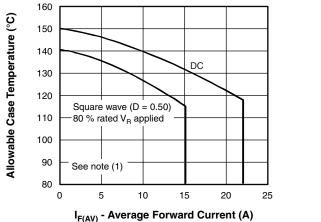
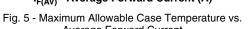


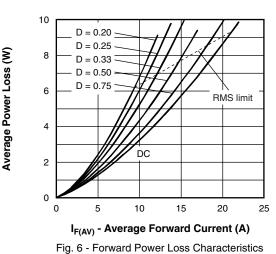
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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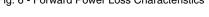
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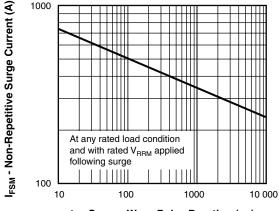






Average Forward Current





t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

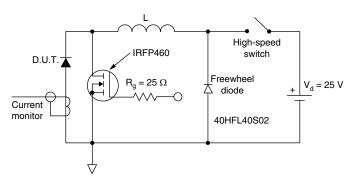


Fig. 8 - Unclamped Inductive Test Circuit

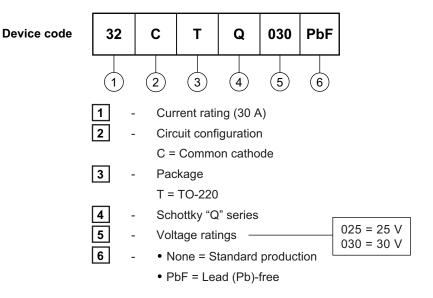
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 80 \% rated V_R$



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ORDERING INFORMATION TABLE



Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95222					
Part marking information	http://www.vishay.com/doc?95225				



Vishay

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